Far-infrared and dc magnetotransport of CaMnO₃-CaRuO₃ superlattices

P. Yordanov,¹ A. V. Boris,¹ J. W. Freeland,² J. J. Kavich,² J. Chakhalian,³ H. N. Lee,⁴ and B. Keimer¹

¹Max-Planck-Institut für Festkörperforschung, D-70569 Stuttgart, Germany

²Advanced Photon Source, Argonne National Laboratory, Argonne, Illinois 60439, USA

³Department of Physics, University of Arkansas, Fayetteville, Arkansas 72701, USA

⁴Materials Science and Technology Division, Oak Ridge National Laboratory, Oak Ridge, Tennessee 37831, USA

(Received 6 April 2011; revised manuscript received 4 May 2011; published 7 July 2011)

We report temperature- and magnetic-field-dependent measurements of the dc resistivity and the far-infrared reflectivity (FIR) (photon energies $\hbar\omega = 50-700 \text{ cm}^{-1}$) of superlattices comprising ten consecutive unit cells of the antiferromagnetic insulator CaMnO₃, and four to ten unit cells of the correlated paramagnetic metal CaRuO₃. Below the Néel temperature of CaMnO₃, the dc resistivity exhibits a logarithmic divergence upon cooling, which is associated with a large negative, isotropic magnetoresistance. The $\omega \rightarrow 0$ extrapolation of the resistivity extracted from the FIR reflectivity, on the other hand, shows a much weaker temperature and field dependence. We attribute this behavior to scattering of itinerant charge carriers in CaRuO₃ from sparse, spatially isolated magnetic defects at the CaMnO₃-CaRuO₃ interfaces. This field-tunable "transport bottleneck" effect may prove useful for functional metal-oxide devices.

DOI: 10.1103/PhysRevB.84.045108

PACS number(s): 73.21.Cd, 75.70.Cn, 73.20.-r

I. INTRODUCTION

Magnetoresistance phenomena in multilayer structures have attracted widespread attention following the discovery of the "giant magnetoresistance" (GMR) effect in heterostructures comprising metals that exhibit negligible magnetoresistance (MR) in the bulk. Recently, related phenomena have also been discovered in heterostructures composed of transitionmetal oxides, including superlattices of the antiferromagnetic insulators LaMnO₃ and SrMnO₃ that replicate the "colossal magnetoresistance" (CMR) effect in the corresponding solid solution,¹⁻³ bilayer structures of the two band insulators LaAlO₃ and SrTiO₃ with a metallic interface subject to Rashba spin-orbit interactions,^{4,5} and superlattices of the correlated metal CaRuO₃ and the antiferromagnetic insulator CaMnO₃.^{6,7} Like the original GMR effect, the sign and magnitude of the MR in oxide heterostructures is expected to be influenced both by the electronic structure of the bulk constituents and by interfacial defects, but it is difficult to discriminate between both factors based on dc-MR measurements alone. Spectroscopic methods, on the other hand, can supply general information about interfacial defects, but rarely yield specific insights into their contribution to the magnetotransport properties. Consequently, the microscopic origin of MR phenomena in oxide heterostructures remains largely unexplored.

Here we report the observation of a large negative dc-magnetoresistance effect in superlattices composed of CaRuO₃ (Refs. 8–11) and CaMnO₃ (Refs. 12–15) and show that a comparison between far-infrared and dc-MR measurements can yield insights into the origin of this behavior. Interest in this system was sparked by the discovery of interface ferromagnetism for temperatures below the Néel temperature of the CaMnO₃ layers.^{6,7} This effect was attributed to a transfer of charge carriers from CaRuO₃ across the interface into an atomically thin layer of CaMnO₃, where they induce spin canting via the double-exchange interaction (Fig. 1). This scenario was supported by density-functional calculations¹⁶ and by a

detailed spectroscopic study.¹⁷ However, the magnetization profile determined by reflectometry with circularly polarized x rays¹⁷ revealed that the ferromagnetic magnetization penetrates more deeply into the CaMnO₃ layers than predicted by the *ab initio* theory, possibly as a consequence of the formation of magnetic polarons that have also been invoked to explain experiments on bulk doped CaMnO₃.^{12–15,18}

In view of the converging experimental and theoretical descriptions, CaRuO₃-CaMnO₃ superlattices are suitable as a model system for spin-dependent transport phenomena in artificially structured oxides. Takahashi et al.⁶ already noted a negative dc MR of about 5% in a magnetic field of 5 T. In contrast to the CMR effect in bulk oxide ferromagnets, this effect persists far below the magnetic ordering temperature. This was attributed to scattering of charge carriers from canted Mn spins at the interface, whose presence was confirmed in subsequent spectroscopic experiments.¹⁷ It has remained unclear, however, to what extent this effect is influenced by interfacial defects that may act as "bottlenecks" for the dc charge transport. In order to elucidate this issue, we have carried out accurate far-infrared (FIR) reflectance experiments as a function of magnetic field. Since the FIR conductivity extracted from these measurements does not require a continuous current path through the entire superlattice, it is much less affected by extended defects such as dislocations and stacking faults, which are nearly unavoidable in multilayer systems. A comparison between FIR and dc transport data on CaMnO₃-CaRuO₃ superlattices indeed indicates a substantial enhancement of the dc MR by spin textures nucleated at extended defects.

The paper is organized as follows. Details of the superlattice samples and the experimental setup are described in Sec. II. In Sec. III A we report the dc transport experiments on the superlattices and reference measurements on CaMnO₃ and CaRuO₃ films. Section III B contains a description of the FIR experiments, and Sec. IV provides a summary of the conclusions.



FIG. 1. (Color online) Schematic picture of a CaMnO₃-CaRuO₃ superlattice. The sketch on the left displays the nominal electron configuration of the constituents: CaMnO₃ in the high-spin state with S = 3/2, and CaRuO₃ in low-spin state with S = 1. Leakage of itinerant electrons from CaRuO₃ into CaMnO₃ induces canting of antiferromagnetically correlated Mn spins close to the interfaces.

II. EXPERIMENTAL DETAILS

Superlattices with six bilayers comprising ten consecutive unit cells (UCs) of CaMnO₃ and N = 4 and ten UCs of CaRuO₃, respectively, were prepared using pulsed-laser deposition on LaAlO₃ (001) substrates. Details of the growth conditions are given in Ref. 17. The structural and electronic properties of the samples investigated here have been characterized extensively by a combination of experimental probes including magnetometry, spectral ellipsometry, x-ray reflectometry, x-ray-absorption spectroscopy, x-ray magnetic circular dichroism, and x-ray resonant magnetic scattering.¹⁷ Briefly, the films are well ordered and fully epitaxial, so that dislocations induced by twin boundaries on the substrate surface¹⁹ must be sparse and localized at the atomic scale. Both superlattices exhibit ferromagnetic signals due to canted Mn spins below the Néel temperature $T_N = 125$ K, whereas no spin polarization was observed on Ru.

The FIR reflectivity measurements were conducted using a custom-built near-normal incidence infrared spectrometer. The apparatus consists of a Fourier transform interferometer (Bruker IFS 66v/S) with spectral resolution of 0.5 cm⁻¹ attached to an 8-T superconducting split-coil magnet system (Oxford Spectromag SM 4000). The configuration to cover the FIR range includes a Hg-arc lamp, a multilayer Bruker T222 beamsplitter, and a IRLabs Si bolometer kept at a temperature of 1.8 K. The sample was placed in the variable temperature insert of the Spectromag system with accessible range 1.6–300 K. The reflectivity spectra were referenced against a gold mirror.

The dc transport measurements were performed in a physical properties measurement system (Quantum Design)

equipped with an 8-T superconducting magnet. The contacts were made by silver paint in a linear four-point geometry. The contact size was ~0.5 mm with a spacing of 1 mm, so that the transport measurements average over any microstructure induced by twin boundaries on the LaAlO₃ substrate (with typical spacings 1–100 μ m). The measurements were made with currents ranging from 10 to 100 nA. The resistivity of the films and superlattices was calculated according to $\rho = R_S \times d$, where R_S is the measured sheet resistance and dis the sample thickness determined by monitoring the intensity oscillation of the reflection high-energy diffraction pattern during growth, and confirmed by x-ray reflectometry.

III. RESULTS AND DISCUSSION

A. dc transport

Before reporting the results of the dc transport measurements on the superlattice samples, we first describe reference measurements on CaRuO₃ and CaMnO₃ films grown under the same conditions. The CaRuO₃ film (Fig. 2) exhibits metallic resistivity with a non-Fermi-liquid temperature dependence best described by a sublinear form in its high-temperature range above 60 K, $\rho(T) \propto T^{\alpha}$ with $\alpha = 0.74$, in qualitative agreement with prior work that had yielded power-law exponents $\alpha = 1/2$ and 3/2 for the high- and low-temperature ranges, respectively.⁸⁻¹¹ This has been ascribed to the influence of spin fluctuations in proximity to a ferromagnetic quantum critical point.

The resistivity of the CaMnO₃ film exhibits insulating, activated behavior (Fig. 3). A least-squares fit to the Arrhenius form $\rho(T) \propto \exp(E_a/k_BT)$ revealed two distinctive temperature regimes. For $300 \ge T \ge 175$ K the data are described by $E_a = 31$ meV, while for $110 \ge T \ge 70$ K, the fit yields $E_a = 48$ meV. Because the optical gap of CaMnO₃ is ~ 1.5 eV,¹² the transport is consistent with thermal excitation of carriers from a shallow impurity level below the conduction band, most likely due to oxygen defects.^{13,14} Interestingly,



FIG. 2. (Color online) Resistivity versus temperature of a CaRuO₃ film with thickness ~ 100 Å. The line shows the result of a power-law fit to the high-temperature range.



FIG. 3. (Color online) Arrhenius plot of the temperaturedependent resistivity of a ~ 100 Å thin film of CaMnO₃. The lines show the results of fits to exponentials with activation energies listed in the legend. The inset shows the data in log ρ -versus-*T* plot.

the linear extrapolations of the fitted curves cross right at the Néel temperature $T_N = 125$ K. The difference in the activation energies of 17 meV is therefore associated with the formation of magnetic polarons.¹⁸ We note that this energy is in agreement with the activation energy for spin diffusion extracted from a recent nuclear magnetic resonance study of bulk CaMnO_{3-x}.¹⁵ The wide intermediate range of temperatures between 175 and 110 K, where $\rho(T)$ deviates from the activated form, can therefore be associated with antiferromagnetic short-range order.

We now turn to the dc resistivity of the superlattices with N = 4 and N = 10 consecutive CaRuO₃ unit cells. The results displayed in Fig. 4 are qualitatively different from those of the constituents shown in Figs. 2 and 3. In particular, the resistivity of both samples exhibits a logarithmic temperature dependence $\rho \propto \ln(1/T)$ upon cooling below $T \sim 90$ K, a temperature close to the Néel temperature of the superlattices.¹⁷ Whereas both reference films exhibit negligible magnetoresistance, the low-temperature resistivity of the superlattices strongly decreases in an external magnetic field H independent of whether it is applied parallel or perpendicular to the superlattice plane (Fig. 4). The corresponding magnetoresistance, defined as $[\rho(H) - \rho(0)]/\rho(0)$, amounts to 12.5% and 25% for N = 4and N = 10 samples, respectively, for H = 8 T (Fig. 5). This is qualitatively similar to, but larger than, the MR determined by Takahashi *et al.*⁶

In principle, a logarithmic term in the resistivity and negative MR can arise from weak localization.²⁰ The isotropic nature of the MR we observe in the CaMnO₃-CaRuO₃ superlattices, however, speaks against this interpretation and indicates a mechanism based on spin-dependent scattering. This is also supported by the observation that the onset of the logarithmic temperature dependence of the resistivity coincides approximately with the onset of magnetic order. Further, the weak hysteresis and absence of saturation of the MR is consistent with the magnetic-field dependence of the net Mn magnetic moment in the magnetically ordered state.¹⁷





FIG. 4. (Color online) Resistivity versus temperature for CaRuO₃-CaMnO₃ superlattices with N = 4 (upper panel) and N = 10 (lower panel) consecutive CaRuO₃ unit cells for H = 0 and 8 T (orange and red, green and blue circles, respectively). Note the logarithmic temperature scale. The straight solid lines (guide to the eyes) indicate a leading logarithmic term in the temperature dependence of resistivity below $T \sim 90$ K.

Logarithmic terms in the temperature-dependent resistivity have been reported for a wide variety of bulk materials within or close to magnetically ordered phases, including some heavy-fermion systems,²¹ cuprate superconductors above their critical magnetic fields,^{22–24} magnetic semiconductors such as Fe_{1-x}Co_xS₂,²⁵ and CaRu_{1-x}Mn_xO₃ solid solutions,^{26–29} but the interpretation of these effects is still under debate. In the latter systems, Kondo scattering due to antiferromagnetic interactions between conduction electrons and localized Mn spins has been invoked to explain this behavior.²⁶ While the antiferromagnetic coupling was confirmed by a recent spectroscopic study,³⁰ quenched disorder due to chemical substitution, possibly associated with phase separation into domains with ferromagnetic and antiferromagnetic order, greatly complicate a quantitative analysis.^{27–29}

Compared to the CaRu_{1-x}Mn_xO₃ solid solution, the transport geometry in CaMnO₃-CaRuO₃ superlattices is better defined, and quenched disorder is greatly reduced. Nonetheless, one generally expects a nonvanishing influence of chemical, structural, and magnetic defects on the transport properties. In particular, in view of the negative MR observed in CaRu_{1-x}Mn_xO₃ (Ref. 28) one cannot rule out *a priori* that the MR observed in the superlattices is influenced by Mn-Ru intermixing at the interfaces. In order to assess the contribution



FIG. 5. (Color online) dc-Magnetoresistance defined as $[\rho(H) - \rho(0)]/\rho(0)$ versus magnetic field *H* of both superlattices at temperature T = 6 K.

of defects to the magnetoresistance, we have carried out optical conductivity measurements, which are much less affected by a small density of isolated defects.

B. Far-infrared spectroscopy

Figure 6 shows near normal-incidence reflectivity spectra of both superlattice samples, along with those of a bare LaAlO₃ substrate and a CaRuO₃ single film on the substrate for comparison. Since the total thicknesses of the films are well below the far-IR wavelengths, the spectra are dominated by the contribution of the substrate, with the metallic response of CaRuO₃ superimposed on the LaAlO₃ phonon features. As a basis for a quantitative model of the reflectivity of the superlattices, we have acquired a reference spectrum of LaAlO₃ under the same experimental conditions. The reflectivity spectra of LaAlO₃ exhibit three main transverse optical (TO) phonon modes at 183, 427, and 648 cm⁻¹ and two longitudinal optical (LO) phonon modes at 277 and 596 cm^{-1} , in agreement with previous reports.^{17,31} The high-frequency LaAlO₃-LO mode is located at 743 cm⁻¹, out of the investigated spectral range.

Magnetic-field-dependent reflectivity measurements were carried out for several temperatures in the range $3 \leq T$ ≤ 300 K, and magnetic fields $0 \leq H \leq 8$ T. When the temperature is reduced below $T \sim 200$ K, we observe clearly discernible magnetic-field-induced changes in the reflectivity over a wide frequency range, for magnetic fields directed both parallel and perpendicular to the superlattice plane. Since the results for both field directions are identical within the experimental error, as in the corresponding dc-MR measurements, we present only data taken in the latter (Kerr) geometry, displayed as the ratio $R(\omega, H)/R(\omega, 0)$ at T = 3 K in Fig. 7. The specific shape of the spectral features in this plot is caused by singularities in the reflectivity of the LaAlO₃ substrate at frequencies where the real part of the dielectric function crosses zero. Thus the moderate magnetic-field dependence of the optical conductivity of itinerant charge carriers in the



FIG. 6. (Color online) Room-temperature reflectivity spectra of a (001) LaAlO₃ substrate (marked as LAO), a CaRuO₃ film (marked as CRO), and the N = 4 and N = 10 superlattices. The inset shows the experimental geometry.

superlattice results in sharp magnetoreflection peaks near the LaAlO₃-LO mode eigenfrequencies.

In our analysis, we treated the superlattices within the effective-medium approach, i.e., as a single composite layer with thickness equal to that of the respective sample.^{17,32,33} This approximation is justified, because the sample thicknesses are well below the wavelengths in the FIR range. In order to quantitatively determine the FIR magnetoresistance, we fitted the magnetoreflection spectra in Fig. 7 to the model spectra of a single Drude-metal layer on a semi-infinite LaAlO₃ substrate following a regression procedure provided by software packages for the characterization of multilayers.³⁴ The initial zero-magnetic-field model parameters were selected following a prior ellipsometry study,¹⁷ where the complex dielectric function of the superlattices was described by a broad Drude response, $\varepsilon(\omega) = \varepsilon_{\infty} - \omega_{pl}^2/(\omega^2 + i\omega\gamma)$, with a ratio of scattering rate and plasma frequency of γ/ω_{pl} = 0.2–0.3, ε_{∞} is the high-frequency contribution to the dielectric function. In the far-IR range for $\omega \ll \gamma \approx 3000 \text{ cm}^{-1}$, $\varepsilon(\omega)$ is almost frequency independent. The measurements thus accurately determine the ratio ω_{pl}^2/γ , which represents the zero-frequency limit of the infrared conductivity, $\sigma_{\omega \to 0} =$ $1/\rho_{\omega\to 0} = 1/4\pi \times \omega_{pl}^2/\gamma$. Figure 7 shows that a fit with this ratio as the only free parameter yields a good description of the magnetic-field-dependent reflectivity of both superlattices over the entire FIR frequency range. We have thus demonstrated that the combination of reflectivity and ellipsometry data allows an accurate extrapolation of the optical data to zero frequency. The temperature- and field-dependent resistivity $\rho_{\omega \to 0} \propto \gamma / \omega_{pl}^2$ determined in this way are presented in Figs. 8 and 9, respectively.

We now compare the results of the $\omega \to 0$ extrapolation of the optical data, $\rho_{\omega\to 0}$ and MR_{$\omega\to 0$}, shown in Figs. 8 and 9 with their counterparts resulting from dc transport measurements, ρ and MR, in Figs. 4 and 5. At high temperatures, the temperature evolution of ρ and $\rho_{\omega\to 0}$ is similar, but ρ is about a factor of 4 larger than $\rho_{\omega\to 0}$. Such differences between both quantities are



FIG. 7. (Color online) Ratio of reflectivity spectra taken for magnetic fields H = 8 and 0 T for N = 4 (upper panel) and N = 10 (lower panel) superlattices. The solid lines are the results of model calculations described in the text.

commonly observed as a result of a small density of isolated, extended defects such as dislocations or microcracks that disrupt the current flow over macroscopic distances, but do not affect the local response to alternating electric fields. Indeed, x-ray reflectivity data on our samples¹⁷ have revealed an effective structural interface roughness of about 5 Å, which is common for oxide superlattices^{35,36} and likely originates in a small density of stacking faults or dislocations nucleated by atomic steps or twin boundaries on the substrate surface. Prior studies of bulk transition-metal oxides using a methodology similar to ours³⁷ have shown that such microstructural defects yield a temperature-independent contribution to the dc resistivity, in agreement with the superlattice data above T_N .

Upon cooling below T_N , however, the dc and FIR responses exhibit profoundly different behavior. In particular, ρ exhibits a pronounced upturn and diverges logarithmically as $T \rightarrow 0$, which can be attributed to a spin-dependent scattering mechanism, as discussed in Sec. II. $\rho_{\omega\rightarrow 0}$, on the other hand, exhibits at most a subtle upturn upon cooling below T_N . At low temperatures, both MR and MR_{$\omega\rightarrow 0$} are qualitatively similar. In particular, they do not show saturation at high fields and exhibit the same ratio of $\sim 2:1$ between N = 4 and N =10 superlattices, confirming that spin-dependent scattering is the dominant source of resistivity at low temperatures. The absolute magnitudes of MR and MR_{$\omega\rightarrow 0$} are, however, very different. This discrepancy indicates that the magnetic scattering centers responsible for the logarithmic term in the



FIG. 8. (Color online) Temperature-dependent resistivity extracted from the extrapolation of the optical response in magnetic fields H = 0 and 8 T for N = 4 (upper panel) and N = 10 superlattices (lower panel). The shaded line marks the Néel temperature.

temperature dependence are sparse and spatially isolated, so that they affect the dc current flow much more than the optical conductivity. This rules out short-range interface roughness generated, for instance, by uniform Ru-Mn intermixing as the



FIG. 9. (Color online) Magnetoresistance defined as $[\rho_{\omega\to 0}(H) - \rho_{\omega\to 0}(0)]/\rho_{\omega\to 0}(0)$ extracted from the extrapolation of the FIR optical response to zero frequency, for both superlattices at temperature T = 3 K.

origin of the MR. Comparison with soft x-ray reflectometry data¹⁷ suggests a different mechanism of this effect. These experiments have provided evidence of spin polarization due to magnetic polarons in the CaMnO₃ layers, analogous to those previously observed in bulk CaMnO₃.^{13,14,18} Scattering of charge carriers in the atomically thin CaRuO₃ layers from polaronic defects trapped at structural faults in the superlattice may then act as spin-dependent transport bottlenecks, thus generating a large dc magnetoresistance effect.

IV. CONCLUSIONS

A detailed comparison of the dc and FIR magnetoresistance in CaMnO₃-CaRuO₃ superlattices has revealed large differences below the Néel temperature of CaMnO₃, which are attributable to scattering of charge carriers in CaRuO₃ from sparse, isolated magnetic defects near the interfaces. These scattering processes generate a contribution to the dc resistivity that diverges as $T \rightarrow 0$. The same experimental approach may also be useful in exploring the origin of similar

- ¹C. Adamo, X. Ke, P. Schiffer, A. Soukiassian, M. Warusawithana,
- L. Maritato, and D. G. Schlom, Appl. Phys. Lett. 92, 112508 (2008).
- ²A. Bhattacharya, S. J. May, S. G. E. te Velthuis, M. Warusawithana, X. Zhai, Bin Jiang, J.-M. Zuo, M. R. Fitzsimmons, S. D. Bader, and
- J. N. Eckstein, Phys. Rev. Lett. 100, 257203 (2008).
 ³H. Yamada, P. H. Xiang, and A. Sawa, Phys. Rev. B 81, 014410 (2010).
- ⁴A. Brinkman, M. Huijben, M. Van Zalk, J. Huijben, U. Zeitler, J. C. Maan, W. G. Van Der Wiel, G. Rijnders, D. H. A. Blank, and H. Hilgenkamp, Nat. Mater. **6**, 493 (2007).
- ⁵A. D. Caviglia, M. Gabay, S. Gariglio, N. Reyren, C. Cancellieri, and J.-M. Triscone, *Phys. Rev. Lett.* **104**, 126803 (2010).
- ⁶K. S. Takahashi, M. Kawasaki, and Y. Tokura, Appl. Phys. Lett. **79**, 1324 (2001).
- ⁷H. Yamada, H. Sato, H. Akoh, N. Kida, T. Arima, M. Kawasaki, and Y. Tokura, Appl. Phys. Lett. **92**, 062508 (2008).
- ⁸G. Cao, O. Korneta, S. Chikara, L. E. DeLong, and P. Schlottmann, Solid State Commun. **148**, 305 (2008).
- ⁹L. Klein, L. Antognazza, T. H. Geballe, M. R. Beasley, and A. Kapitulnik, Phys. Rev. B **60**, 1448 (1999).
- ¹⁰L. Capogna, A. P. Mackenzie, R. S. Perry, S. A. Grigera, L. M. Galvin, P. Raychaudhuri, A. J. Schofield, C. S. Alexander, G. Cao, S. R. Julian, and Y. Maeno, Phys. Rev. Lett. 88, 076602 (2002).
- ¹¹Y. S. Lee, Jaejun Yu, J. S. Lee, T. W. Noh, T.-H. Gimm, Han-Yong Choi, and C. B. Eom, Phys. Rev. B **66**, 041104 (2002).
- ¹²N. N. Loshkareva, L. V. Nomerovannaya, E. V. Mostovshchikova, A. A. Makhnev, Yu. P. Sukhorukov, N. I. Solin, T. I. Arbuzova, S. V. Naumov, N. V. Kostromitina, A. M. Balbashov, and L. N. Rybina, Phys. Rev. B **70**, 224406 (2004).
- ¹³J. J. Neumeier and J. L. Cohn, Phys. Rev. B 61, 14319 (2000).
- ¹⁴C. Chiorescu, J. L. Cohn, and J. J. Neumeier, Phys. Rev. B 76, 020404 (2007).
- ¹⁵A. Trokiner, S. Verkhovskii, A. Yakubovskii, A. Gerashenko, P. Monod, K. Kumagai, K. Mikhalev, A. Buzlukov, Z. Litvinova, O. Gorbenko, A. Kaul, and M. Kartavtzeva, Phys. Rev. B **79**, 214414 (2009).

logarithmic terms in the low-temperature resistivities of a variety of bulk systems.^{21–29} In contrast to bulk solid solutions, the CaMnO₃-CaRuO₃ superlattices have the advantage that the contact between the itinerant charge carriers and the magnetic scattering centers is limited to well-defined interfaces. Tailoring of spin textures at these interfaces may therefore open up new perspectives for functional oxide devices.

ACKNOWLEDGMENTS

Work in Stuttgart was partially supported by the German Science Foundation under collaborative Grant No. SFB/TRR80. Work at Argonne, including the Advanced Photon Source, and the Center for Nanoscale Materials is supported by the US Department of Energy, Office of Science, under Contract No. DE-AC02-06CH11357. J.C. was supported by DOD-ARO under Grant No. W911NF-08-1-0186 and NSF under Contract No. DMR-0747808. H.N.L. was sponsored by the Materials Sciences and Engineering Division, Office of Basic Energy Sciences, US Department of Energy.

- ¹⁶B. R. K. Nanda, S. Satpathy, and M. S. Springborg, Phys. Rev. Lett. 98, 216804 (2007).
- ¹⁷J. W. Freeland, J. Chakhalian, A. V. Boris, J.-M. Tonnerre, J. J. Kavich, P. Yordanov, S. Grenier, P. Zschack, E. Karapetrova, P. Popovich, H. N. Lee, and B. Keimer, Phys. Rev. B **81**, 094414 (2010).
- ¹⁸H. Meskine, T. Saha-Dasgupta, and S. Satpathy, Phys. Rev. Lett. **92**, 056401 (2004); H. Meskine and S. Satpathy, J. Phys.: Condens. Matter **17**, 1889 (2005).
- ¹⁹E. B. McDaniel and J. W. P. Hsu, J. Appl. Phys. **80**, 1085 (1996).
- ²⁰For a review, see P. A. Lee and T. V. Ramakrishnan, Rev. Mod. Phys. **57**, 287 (1985).
- ²¹For a review, see H. von Löhneysen, A. Rosch, M. Vojta, and P. Wölfle, Rev. Mod. Phys. **79**, 1015 (2007).
- ²²Y. Ando, G. S. Boebinger, A. Passner, T. Kimura, and K. Kishio, Phys. Rev. Lett. **75**, 4662 (1995).
- ²³S. Ono, Y. Ando, T. Murayama, F. F. Balakirev, J. B. Betts, and G. S. Boebinger, Phys. Rev. Lett. 85, 638 (2000).
- ²⁴T. Sekitani, M. Naito, and N. Miura, Phys. Rev. B **67**, 174503 (2003).
- ²⁵S. Guo, D. P. Young, R. T. Macaluso, D. A. Browne, N. L. Henderson, J. Y. Chan, L. L. Henry, and J. F. DiTusa, Phys. Rev. Lett. **100**, 017209 (2008).
- ²⁶T. Sugiyama and N. Tsuda, J. Phys. Soc. Jpn. **68**, 1306 (1999).
- ²⁷A. Maignan, C. Martin, M. Hervieu, and B. Raveau, Solid State Commun. **117**, 377 (2001).
- ²⁸L. Pi, S. Hébert, C. Martin, A. Maignan, and B. Raveau, Phys. Rev. B **67**, 024430 (2003).
- ²⁹V. Markovich, M. Auslender, I. Fita, R. Puzniak, C. Martin, A. Wisniewski, A. Maignan, B. Raveau, and G. Gorodetsky, Phys. Rev. B **73**, 014416 (2006).
- ³⁰K. Terai, K. Yoshii, Y. Takeda, S. I. Fujimori, Y. Saitoh, K. Ohwada, T. Inami, T. Okane, M. Arita, K. Shimada, H. Namatame, M. Taniguchi, K. Kobayashi, M. Kobayashi, and A. Fujimori, Phys. Rev. B 77, 115128 (2008).

- ³¹A. V. Boris, N. N. Kovaleva, A. V. Bazhenov, A. V. Samoilov, N. C. Yeh, and R. P. Vasquez, J. Appl. Phys. **81**, 5756 (1997).
- ³²A. Dubroka, G. Cristiani, H.-U. Habermeier, and J. Humlicek, Thin Solid Films 455–456, 172 (2004).
- ³³S. S. A. Seo, W. S. Choi, H. N. Lee, L. Yu, K. W. Kim, C. Bernhard, and T. W. Noh, Phys. Rev. Lett. **99**, 266801 (2007).
- ³⁴A. V. Tikhonravov and M. K. Trubetskov, OPTILAYER thin film software, [http://www.optilayer.com]; A. Kuzmenko, RefFIT software package, University of Geneva, [http://optics.unige.ch/ alexey/reffit.html].
- ³⁵J. Stahn, J. Chakhalian, Ch. Niedermayer, J. Hoppler, T. Gutberlet, J. Voigt, F. Treubel, H-U. Habermeier, G. Cristiani, B. Keimer, and C. Bernhard, Phys. Rev. B **71**, 140509(R) (2005).
- ³⁶E. Benckiser, M. W. Haverkort, S. Brück, E. Goering, S. Macke, A. Franó, X. Yang, O. K. Andersen, G. Cristiani, H.-U. Habermeier, A. V. Boris, I. Zegkinoglou, P. Wochner, H.-J. Kim, V. Hinkov, and B. Keimer, Nat. Mater. **10**, 189 (2011).
- ³⁷A. Lebon, P. Adler, C. Bernhard, A. V. Boris, A. V. Pimenov, A. Maljuk, C. T. Lin, C. Ulrich, and B. Keimer, Phys. Rev. Lett. 92, 037202 (2004).